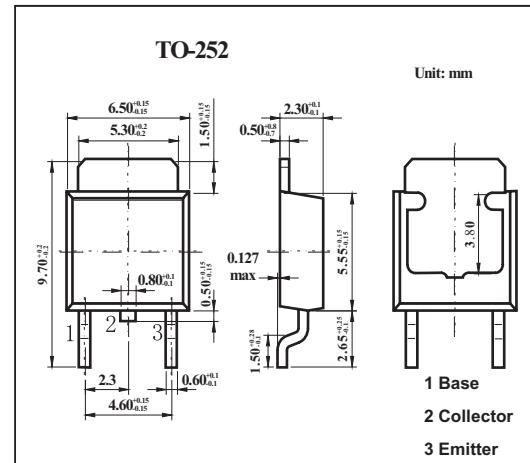


2SD1253,2SD1253A

■ Features

- High forward current transfer ratio hFE which has satisfactory linearity.
- Low collector to emitter saturation voltage V_{CE(sat)}.



■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	60	V
2SD1253A		80	V
Collector-emitter voltage	V _{CEO}	60	V
2SD1253A		80	V
Emitter-base voltage	V _{EBO}	5	V
Collector current	I _C	4	A
Peak collector current	I _{CP}	8	A
Collector power dissipation	P _C	1.3	W
T _a = 25°C		40	
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

2SD1253,2SD1253A

■ Electrical Characteristics $T_a = 25^\circ\text{C}$

Parameter	Symbol	Testconditons	Min	Typ	Max	Unit
Collector-emitter voltage 2SD1253 2SD1253A	V _{CEO}	$I_C = 30 \text{ mA}, I_B = 0$	60			V
			80			V
Base-emitter voltage	V _{BE}	$V_{CE} = 4 \text{ V}, I_C = 3 \text{ A}$			2	V
Collector-emitter cutoff current 2SD1253 2SD1253A	I _{CES}	$V_{CE} = 60 \text{ V}, V_{BE} = 0$		400		μA
		$V_{CE} = 80 \text{ V}, V_{BE} = 0$		400		μA
Collector-emitter cutoff current 2SD1253 2SD1253A	I _{CEO}	$V_{CE} = 30 \text{ V}, I_B = 0$		700		μA
		$V_{CE} = 60 \text{ V}, I_B = 0$		700		μA
Emitter-base cutoff current	I _{EBO}	$V_{EB} = 5 \text{ V}, I_C = 0$		1		mA
Forward current transfer ratio	h _{FE}	$V_{CE} = 4 \text{ V}, I_C = 1 \text{ A}$	40		250	
Forward current transfer ratio		$V_{CE} = 4 \text{ V}, I_C = 3 \text{ A}$	15			
Collector-emitter saturation voltage	V _{CES(sat)}	$I_C = 4 \text{ A}, I_B = 0.4 \text{ A}$			1.5	V
Transition frequency	f _T	$V_{CE} = 5 \text{ V}, I_C = 0.5 \text{ A}, f = 1 \text{ MHz}$		20		MHz
Turn-on time	t _{on}	I _C =4A I _{B1} =-I _{B2} =0.4 A		0.4		μs
Storage time	t _{stg}			1.2		μs
Fall time	t _f	V _{CC} =50V		0.5		μs

■ h_{FE} Classification

Rank	R	Q	P
h _{FE}	40~90	70~150	120~250